



**Nano
Fabrication
Center**

PECVD

Standard Operating Procedure

Written by Danielle Amit Awaskar

AL 7.38 mTorr Production	PM1 30.0 mTorr Production	Recipe 10.00	Host Equipment Off-Line Disabled	Current User system	AL PM1
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Help Alarm: Rec 0

Jobs

Recipes

- SiNx
- SiNx
- SiNx
- SiNx
- SiNx
- SiO2
- SiO2
- SiO2
- SiO2
- SiO2

Go To Recipe Temperature

Vent After Job Process in PM, No Transfer

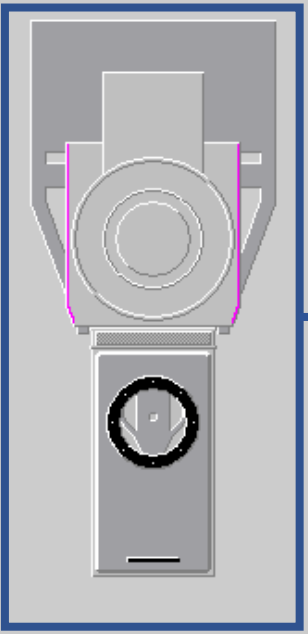
Selected Recipe:
SiO2 PreDep

Material ID:

Start Job **Stop Job**

Current Job
Job Status: Idle
Recipe Name:

Completed Run 0 of 0



Process State: Standby

Seq. Name:

Step No:

Step Name:

Parameter	Setpoint	Actual	Unit
Time	0.0	10.0	s
Pressure		30.0	mTorr
Throttle Position		100.0	%
RF Forward Pwr	0.0	0.0	W
RF Reflected Pwr	---	0.0	W
LF Forward Pwr	0.0	0.0	W
LF Reflected Pwr	---	0.0	W
LF Pulse Duty Cycl	---	100.0	%
LF Pulse Frequency	---		Hz
SiH4He	0.0	0.1	sccm
NH3	0.0	0.0	sccm
N2O	0.0	0.1	sccm
SF6	0.0	0.0	sccm
He	0.0	0.0	sccm
N2	0.0	0.0	sccm
Up Electrode Temp	200.0	199.9	°C
Low Electrode Temp	330.0	329.0	°C
RF AMN Mode	Automatic	Automatic	
RF AMN Load Pos		39.3	%

Go To Standby Temperature

Lock

Pump Vent

Vacuum

Job Start Adjust Manage AMS AMS Editor

Jobs System Editors Setup Maintain Data Log Alarms Help

BACK FORWARD

Go To...

A

B

C

D

E

F

G

H

I

J

K

L

Standard Operating Procedure (SOP)

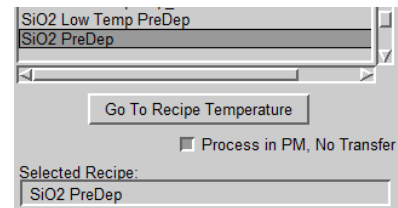
Plasma-Enhanced Chemical Vapor Deposition (PE-CVD)

- 1) Turn on the nitrogen switch, labeled “N2 PURGE VALVE”, located on the left side of the computer screen.



Step 1 – Conditioning

- 2) Choose a suitable conditioning recipe for the material you plan to deposit from the list of recipes [A] and click on it.
 - “SiNx PreDep” - for deposition of SiNx (About 12 minutes)
 - “SiO2 PreDep” - for deposition of SiO₂ (About 6 minutes)



Confirm that the selected recipe appears in “Selected Recipe” [D].

- 3) Click on “Go To Recipe Temperature” [B].

On the right side of the screen, you will be able to see the temperature of the electrodes defined in the recipe and the actual temperature of the electrodes [L].

Up Electrode Temp	200.0	199.0	°C
Low Electrode Temp	300.0	298.6	°C

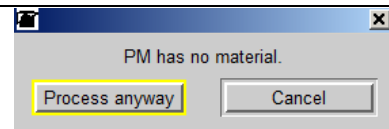
Wait for the temperature of the electrodes to reach the desired temperature.

- 4) Click on “Process in PM, no Transfer” [C]. The button will be gray and not bright.

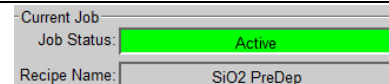


- 5) Click on “Start Job” [E].

- 6) A notification will pop up saying “PM has no material”, select “Process Anyway”.



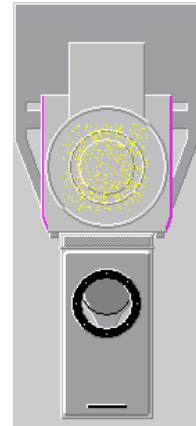
- 7) Gases are supplied to the chamber [K] and the conditioning process begins. You can see that the process started [F], the number of steps in the process and what step you are in [I] and the duration of the step [J].



Process State:	Ready		
Seq. Name:	SiO2 PreDep		
Step No.:	4/6		
Step Name:	SiO2 PreDep		
Parameter	Setpoint	Actual	Unit
Time	300.0	96.871	s

In the meantime, you can clean up your sample.

8) When the plasma starts, you can see it in [G].



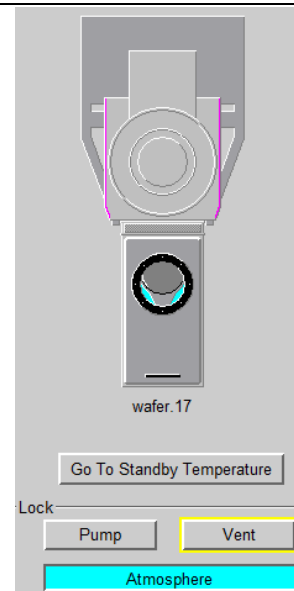
9) It can be understood that the process is over when it is not written that you are in the middle of a process [F] and that the lines of step number and step name are empty [I].

Current Job	
Job Status:	Idle
Recipe Name:	SiO2 PreDep

Process State:	Ready
Seq. Name:	SiO2 PreDep
Step No:	
Step Name:	

Step 2 – Your process

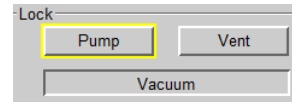
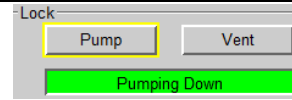
10) Press “Vent” [H] and wait until it turns blue and says “Atmosphere”.



11) Now you can open the load lock and place your sample in the sample holder with tweezers to **avoid burns from its high temperature (300°C)**. Please use appropriate safety equipment, such as tweezers with insulated handles. Close the lid of the load lock.

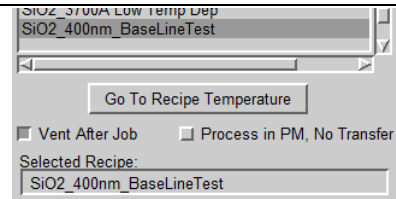


12) Press “**Pump**” and wait until it says “Vacuum” [H].



13) Choose **your deposit recipe** from the list of recipes [A] and click on it.

The name of the recipe you selected should appear in “Selected Recipe” [D].



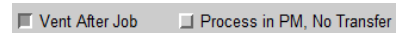
14) Click on “**Go To Recipe Temperature**” [B].

Wait for the temperature of the electrodes to reach the desired temperature.

Up Electrode Temp	200.0	199.0	°C
Low Electrode Temp	300.0	298.6	°C

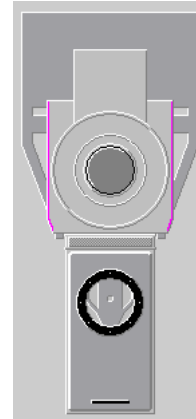
15) Click on “**Process in PM, no Transfer**” [C]. *The button will be bright and not gray.*

And click on “**Vent After Job**” [C]. *The button will be gray and not bright.*



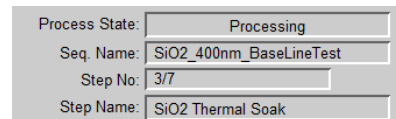
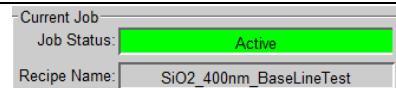
16) Click on “**Start Job**” [E].

17) *First, the arm will insert the sample from the load lock into the chamber. Then it will return empty to load lock and close the gate valve (that separates the load lock from the chamber).*



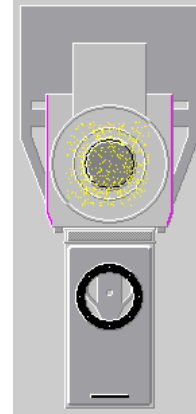
18) *Now the gases are supplied to the chamber [K] and your process begins.*

You can see that the process started [F], the number of steps in the process, what step you are in [I] and how long the step takes [J].

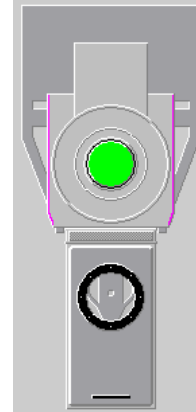


Parameter	Setpoint	Actual	Unit
Time	180.0	147.496	s

19) When the plasma starts, you can see it in [G].



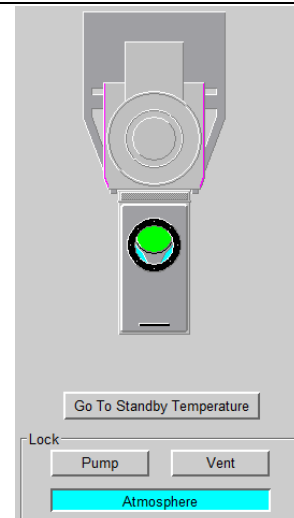
20) It can be understood that the process is over when the wafer turns green [G] and that the lines of step number and step name are empty [I]. The arm still needs to take your sample out of the chamber to load lock, so it still says that the job is active.



Current Job:	
Job Status:	Active
Recipe Name:	SiO2_400nm_BaseLineTest

Process State:	Ready
Seq. Name:	SiO2_400nm_BaseLineTest
Step No.:	
Step Name:	

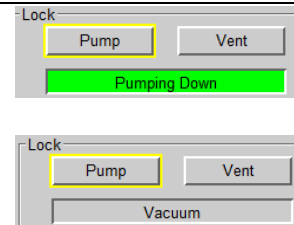
21) The system will vent by itself because we selected it in step 15 so wait until it turns blue and says "Atmosphere".



22) Now you can open the load lock and take out your sample from the sample holder with tweezers to **avoid burns from its high temperature (300°C)**. Please use appropriate safety equipment, such as tweezers with insulated handles. Close the lid of the load lock.



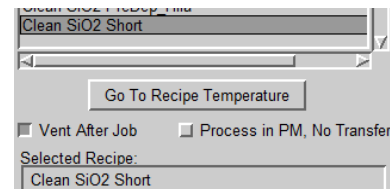
23) Press **“Pump”** and wait until it says **“Vacuum”** [H].



Step 3 – Cleaning

24) Choose a suitable cleaning program for the material you deposited from the list of recipes [A] and click on it.

- **“Clean SiNx Short”** - for deposit of less than 1 μm of SiN_x (About 26 minutes)
- **“Clean SiNx Long”** - for deposit of more than 1 μm of SiN_x (About 51 minutes)
- **“Clean SiO₂ Short”** - for deposit of less than 1 μm of SiO₂ (About 26 minutes)
- **“Clean SiO₂ Long”** - for deposit of more than 1 μm of SiO₂ (About 51 minutes)



The name of the recipe you selected should appear in **“Selected recipe”** [D].

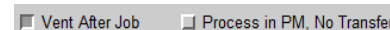
25) Click on **“Go To Recipe Temperature”** [B].

Wait for the temperature of the electrodes to reach the desired temperature.

Up Electrode Temp	200.0	199.0	°C
Low Electrode Temp	300.0	298.6	°C

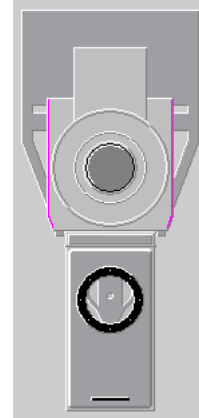
26) Click on **“Process in PM, no Transfer”** [C]. *The button will be bright and not gray.*

And click on **“Vent After Job”** [C]. *The button will be gray and not bright.*



27) Click on **“Start Job”** [E].

28) First, the arm will insert the sample from the load lock into the chamber. Then it will return empty to load lock and close the gate valve (that separates the load lock from the chamber).



29) Now the gases are supplied to the chamber [K] and the cleaning process begins. You can see that the process started [F], the number of steps in the process, what step you are in [I] and how long the step takes [J].

Current Job:
 Job Status: **Active**
 Recipe Name: Clean SiO2 Short

Process State: Processing
 Seq. Name: Clean SiO2 Short
 Step No: 4/8
 Step Name: Clean OE Ox Short

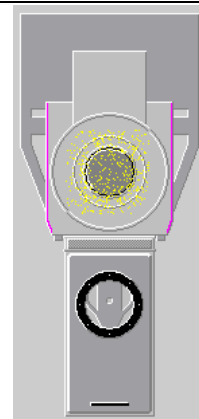
Parameter	Setpoint	Actual	Unit
Time	900.0	22.427	s

30) Fill in the **Log-Book** and write down all the details of the process you ran.

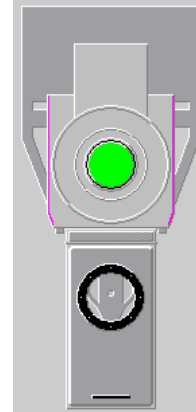
Log-Book: PECVD

Row	Date	User Name	Process Name	Mean T13 (min)	Cleaning Process Name	Machine Error/Comments
11						
12						
13						
14						
15						
16						
17						
18						
19						
20						
21						
22						
23						
24						
25						
26						
27						
28						
29						
30						

31) When the plasma starts, you can see it in [G].

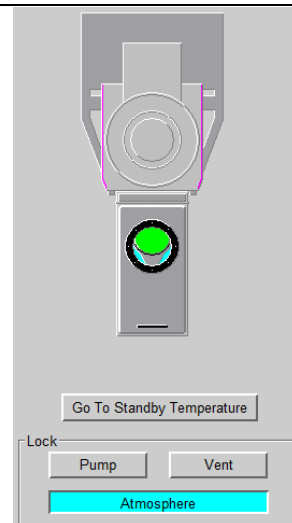


32) It can be understood that the process is over when the wafer turns green [G] and that the lines of step number and step name are empty. The arm still needs to take your sample out of the chamber to load lock, so it still says that the job is active.



Current Job	
Job Status:	Active
Recipe Name:	Clean SiO2 Short
Process State:	Ready
Seq. Name:	Clean SiO2 Short
Step No.:	
Step Name:	

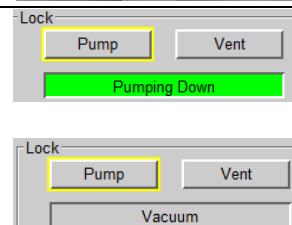
33) The system will vent by itself because we selected it in step 26 so wait until it turns blue and says "Atmosphere".



34) Now you can open the load lock and check that the holder is indeed clean. **A reminder: exercise caution to avoid burns from its high temperature (300°C).** Close the lid of the load lock.



35) Press "Pump" and wait until it says "Vacuum" [H].



36) **Turn off** the nitrogen switch: “**N2 PURGE VALVE**”, which is on the left side of the computer screen.



37) Before leaving, conduct a final check to ensure the work environment is clean, and all equipment is properly stored.

If you encounter any difficulties or problems, please contact the person in charge of the device- Danielle Amit Awaskar at extension 2129